

MA1U152WA

Silicon epitaxial planer type

For switching circuits

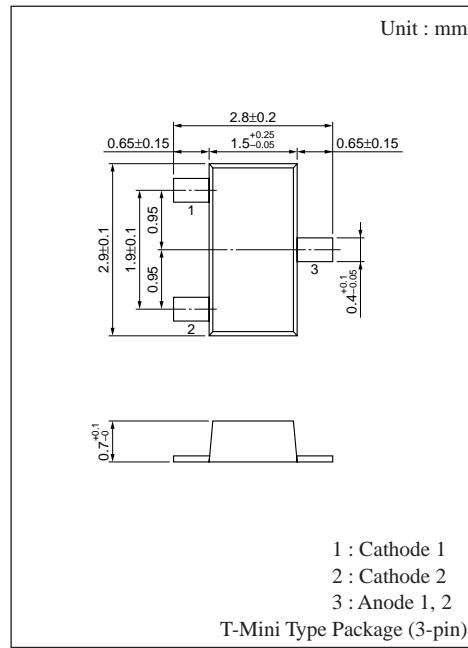
■ Features

- Package thickness as small as 0.7mm, most favorite for thinning of equipment
- Flat lead type, with improved mounting efficiency and solderability in the high-speed mounting machine
- Anode common connection type

■ Absolute Maximum Ratings (Ta= 25°C)

| Parameter | Symbol | Rating | Unit |
|---|--------------------|-------------|------|
| Reverse voltage (DC) | V _R | 80 | V |
| Peak reverse voltage | V _{RM} | 80 | V |
| Forward current (DC) | I _F | 100 | mA |
| Double | I _F | 150 | |
| Peak forward current | I _{FM} | 225 | mA |
| Double | I _{FM} | 340 | |
| Non-repetitive peak forward surge current | I _{FSM} * | 500 | mA |
| Double | I _{FSM} * | 750 | |
| Junction temperature | T _j | 150 | °C |
| Storage temperature | T _{stg} | -55 to +150 | °C |

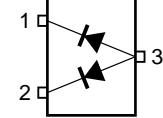
* t=1s



1 : Cathode 1
2 : Cathode 2
3 : Anode 1, 2
T-Mini Type Package (3-pin)

Marking Symbol : MO

■ Internal Connection



■ Electrical Characteristics (Ta= 25°C)

| Parameter | Symbol | Condition | min | typ | max | Unit |
|-----------------------|-------------------|--|-----|-----|-----|------|
| Reverse current (DC) | I _R | V _R = 75V | | | 0.1 | μA |
| Forward voltage (DC) | V _F | I _F =100mA | | | 1.2 | V |
| Reverse voltage (DC) | V _R | I _R =100μA | 80 | | | V |
| Terminal capacitance | C _t | V _R = 0V, f=1MHz | | | 15 | pF |
| Reverse recovery time | t _{rr} * | I _F =10mA, V _R = 6V I _{rr} = 0.1 · I _R , R _L =100Ω | | | 10 | ns |

Note 1 : Rated input/output frequency : 100MHz

2 : * t_{rr} measuring circuit

■ Marking

